



DUAL N-CHANNEL ENHANCEMENT MODE MOSFET

Product Summary

| V _{(BR)DSS} | R _{DS(ON)} | I _D T _A = 25°C |
|----------------------|------------------------------|---|
| 30V | 4.2Ω @ V _{GS} = 5V | 200mA |
| | 2.8Ω @ V _{GS} = 10V | 260mA |

Description

This new generation MOSFET has been designed to minimize the on-state resistance (R_{DS(on)}) and yet maintain superior switching performance, making it ideal for high efficiency power management applications.

Applications

- DC-DC Converters
- Power management functions
- Battery Operated Systems and Solid-State Relays
- Drivers: Relays, Solenoids, Lamps, Hammers, Displays, Memories, Transistors, etc

Features

- Dual N-Channel MOSFET
- Low On-Resistance
- Low Input Capacitance
- Fast Switching Speed
- Small Surface Mount Package
- ESD Protected Gate
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

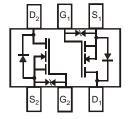
Mechanical Data

- Case: SOT563
- Case Material: Molded Plastic. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Matte Tin Finish annealed over Alloy 42 leadframe (Lead Free Plating). Solderable per MIL-STD-202, Method 208
- Terminal Connections: See Diagram
- Weight: 0.006 grams (approximate)





Top View



Top View Internal Schematic

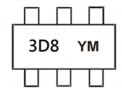
Ordering Information (Note 4)

| Part Number | Case | Packaging |
|--------------|--------|--------------------|
| DMN63D8LV-7 | SOT563 | 3,000/Tape & Reel |
| DMN63D8LV-13 | SOT563 | 10,000/Tape & Reel |

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
- 2. See http://www.diodes.com for more information about Diodes Incorporated's definitions of Hallogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at http://www.diodes.com.

Marking Information



3D8 = Product Type Marking Code YM = Date Code Marking Y = Year (ex: Z = 2012) M = Month (ex: 9 = September)

Date Code Key

| Year | 201 | 1 | 2012 | | 2013 | 20 | 14 | 2015 | | 2016 | 2 | 2017 |
|-------|-----|-----|------|-----|------|-----|-----|------|-----|------|-----|------|
| Code | Υ | | Z | | Α | | В | С | | D | | E |
| Month | Jan | Feb | Mar | Apr | May | Jun | Jul | Aug | Sep | Oct | Nov | Dec |
| Code | 1 | 2 | 3 | 4 | 5 | 6 | 7 | 8 | 9 | 0 | N | D |

DMN63D8LV Document number: DS36022 Rev. 2 - 2



Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

| Characteristic | | | Symbol | Value | Units |
|--|-----------------|--|------------------|------------|-------|
| Drain-Source Voltage | | | V_{DSS} | 30 | V |
| Gate-Source Voltage | | | V _{GSS} | ±20 | V |
| Continuous Drain Current (Note 5) V _{GS} =10V | Steady State | T _A = 25°C T _A = 70°C | I _D | 260 200 | mA |
| Continuous Drain Current (Note 5) V _{GS} = 5V | Steady State | T _A = 25°C T _A = 70°C | I _D | 220 160 | mA |
| Pulsed Drain Current (10µs pulse, duty cycle = 1%) | I _{DM} | 800 | mA | | |

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

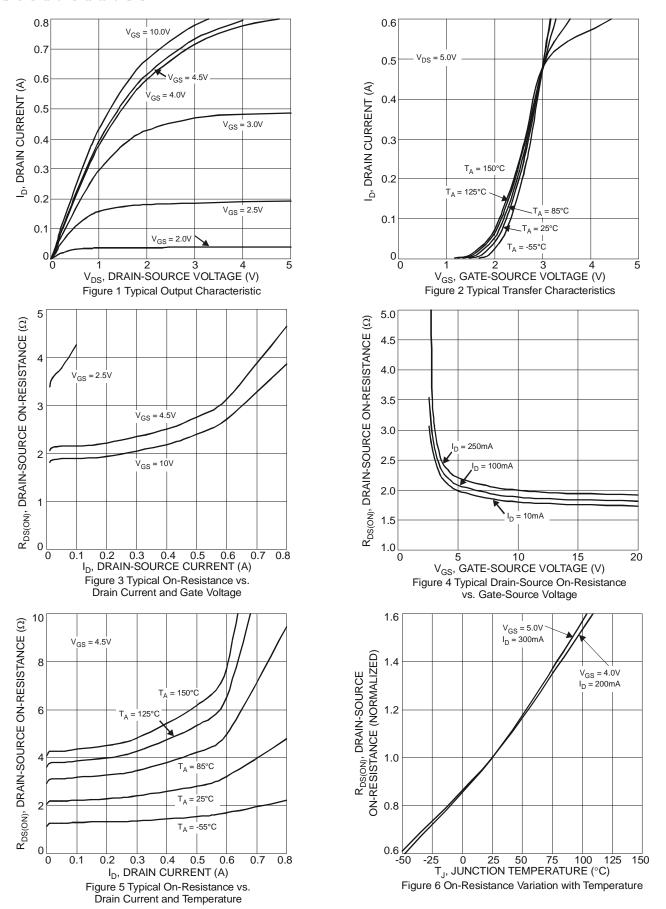
| Characteristic | | Symbol | Value | Units |
|---|----------|-----------------|------------|-------|
| Total Power Dissipation | (Note 5) | P_{D} | 450 | mW |
| Thermal Resistance, Junction to Ambient | (Note 5) | $R_{\theta JA}$ | 281 | °C/W |
| Operating and Storage Temperature Range | | $T_{J,}T_{STG}$ | -55 to 150 | °C |

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

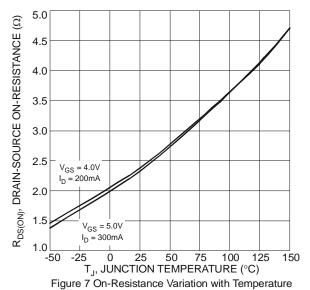
| Characteristic | Symbol | Min | Тур | Max | Unit | Test Condition | |
|--|----------------------|-----|---------|-------|----------|---|--|
| OFF CHARACTERISTICS (Note 6) | - J | | . , , , | | <u> </u> | | |
| Drain-Source Breakdown Voltage | BV _{DSS} | 30 | | _ | V | $V_{GS} = 0V, I_D = 250 \mu A$ | |
| Zero Gate Voltage Drain Current | I _{DSS} | _ | _ | 1.0 | μΑ | V _{DS} = 30V, V _{GS} = 0V | |
| Gate-Body Leakage | I _{GSS} | _ | | ±10.0 | μΑ | $V_{GS} = \pm 20V, V_{DS} = 0V$ | |
| ON CHARACTERISTICS (Note 6) | | | | | | | |
| Gate Threshold Voltage | $V_{GS(th)}$ | 0.8 | | 1.5 | V | $V_{DS} = V_{GS}, I_D = 250 \mu A$ | |
| | | _ | | 2.8 | | $V_{GS} = 10.0V, I_D = 250mA$ | |
| | | | | 3.8 | | $V_{GS} = 5.0V, I_D = 250mA$ | |
| Static Drain-Source On-Resistance | R _{DS (ON)} | | | 4.2 | Ω | $V_{GS} = 4.5V, I_D = 250mA$ | |
| | | _ | | 4.5 | | $V_{GS} = 4.0V, I_D = 250mA$ | |
| | | _ | _ | 13 | | $V_{GS} = 2.5V, I_D = 10mA$ | |
| Forward Transconductance | g _{FS} | 80 | _ | _ | mS | V _{DS} = 10V, I _D = 0.115A | |
| Diode Forward Voltage | V _{SD} | - | 8.0 | 1.2 | V | $V_{GS} = 0V, I_{S} = 115mA$ | |
| DYNAMIC CHARACTERISTICS (Note 7) | | | | | | | |
| Input Capacitance | Ciss | | 22.0 | _ | | | |
| Output Capacitance | Coss | | 3.2 | _ | pF | $V_{DS} = 25V, V_{GS} = 0V, f = 1.0MHz$ | |
| Reverse Transfer Capacitance | C _{rss} | _ | 2.0 | _ | | | |
| Gate Resistance | R_{G} | _ | 79.9 | _ | Ω | $V_{DS} = 0V, V_{GS} = 0V, f = 1.0MHz$ | |
| Total Gate Charge V _{GS} = 10V | Qg | | 0.87 | _ | | | |
| Total Gate Charge V _{GS} = 4.5V | Qg | _ | 0.43 | _ | nC | $V_{GS} = 10V, V_{DS} = 30V,$ | |
| Gate-Source Charge | Q _{gs} | | 0.11 | _ | nC | $I_D = 150 \text{mA}$ | |
| Gate-Drain Charge | Q _{gd} | _ | 0.11 | _ | | | |
| Turn-On Delay Time | t _{D(on)} | _ | 3.3 | _ | | | |
| Turn-On Rise Time | t _r | _ | 3.2 | _ | nS | $V_{DD} = 30V$, $I_{D} = 0.115A$, $V_{GEN} = 10V$. | |
| Turn-Off Delay Time | t _{D(off)} | _ | 12.0 | _ | nS | $R_{GEN} = 25\Omega$ | |
| Turn-Off Fall Time | t _f | _ | 6.3 | _ | | | |

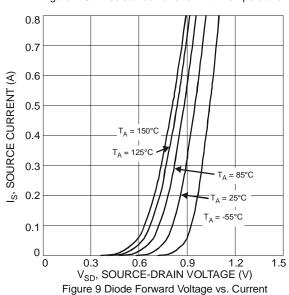
- 5. Device mounted on FR-4 PC board, with minimum recommended pad layout, single sided.
- 6 .Short duration pulse test used to minimize self-heating effect.
- 7. Guaranteed by design. Not subject to production testing.











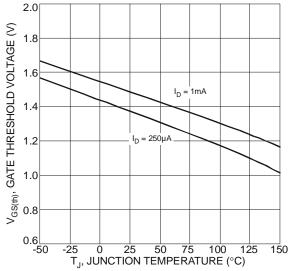
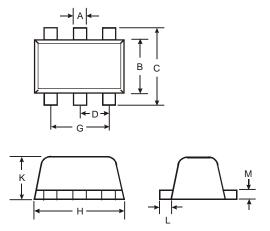


Figure 8 Gate Threshold Variation vs. Ambient Temperature



Package Outline Dimensions

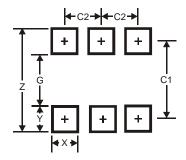
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for latest version.



| SOT563 | | | | | | | |
|--------|----------------------|------|------|--|--|--|--|
| Dim | Min | Max | Тур | | | | |
| Α | 0.15 | 0.30 | 0.20 | | | | |
| В | 1.10 | 1.25 | 1.20 | | | | |
| С | 1.55 | 1.70 | 1.60 | | | | |
| D | - | - | 0.50 | | | | |
| G | 0.90 | 1.10 | 1.00 | | | | |
| Н | 1.50 | 1.70 | 1.60 | | | | |
| K | 0.55 | 0.60 | 0.60 | | | | |
| L | 0.10 | 0.30 | 0.20 | | | | |
| M | 0.10 | 0.18 | 0.11 | | | | |
| All | All Dimensions in mm | | | | | | |

Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



| Dimensions | Value (in mm) |
|------------|---------------|
| Z | 2.2 |
| G | 1.2 |
| Х | 0.375 |
| Y | 0.5 |
| C1 | 1.7 |
| C2 | 0.5 |



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